

Analog signal sense with isolation

Introduction

In digital controlled power supplies, there are several voltage or current signals that need to be sensed at the analog to digital converter (ADC) peripheral of the microcontroller (MCU). The situation becomes challenging when the isolation between signal sense ground (GND) and microcontroller GND is required.

This technical note is highlighting one of the alternative solutions to sense voltage or current signal at ADC peripheral of MCU with isolation. Though there are dedicated integrated chips (IC's) available to address the above requirements, they have several limitations, such as sense signal gain, bandwidth of operational amplifier, etc. This alternate solution not only overcomes the mentioned limitations, but is also cost-effective.

Figure 1. Daughter board developed - top view

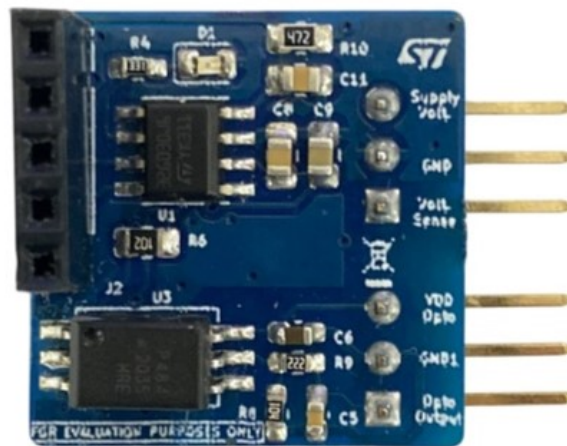
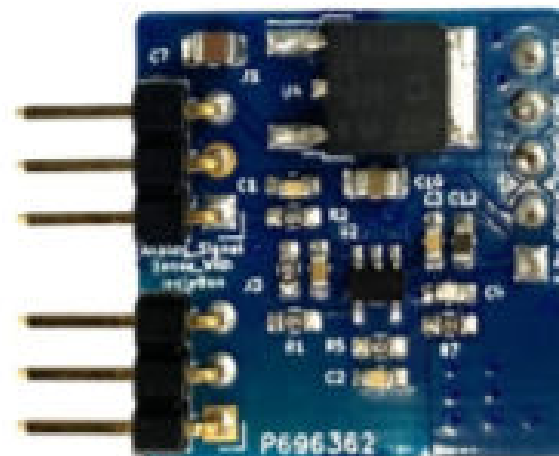
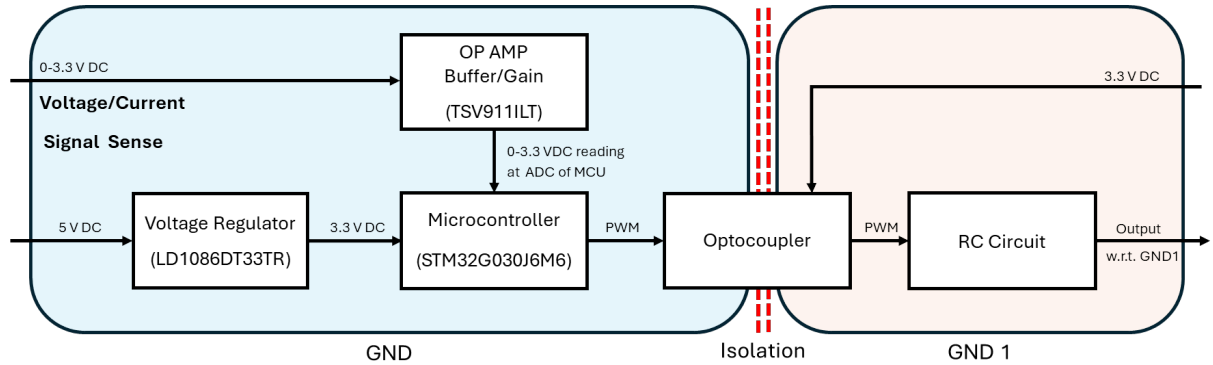


Figure 2. Daughter board developed - bottom view



1 Overview and block diagram

Figure 3. Architectural block diagram



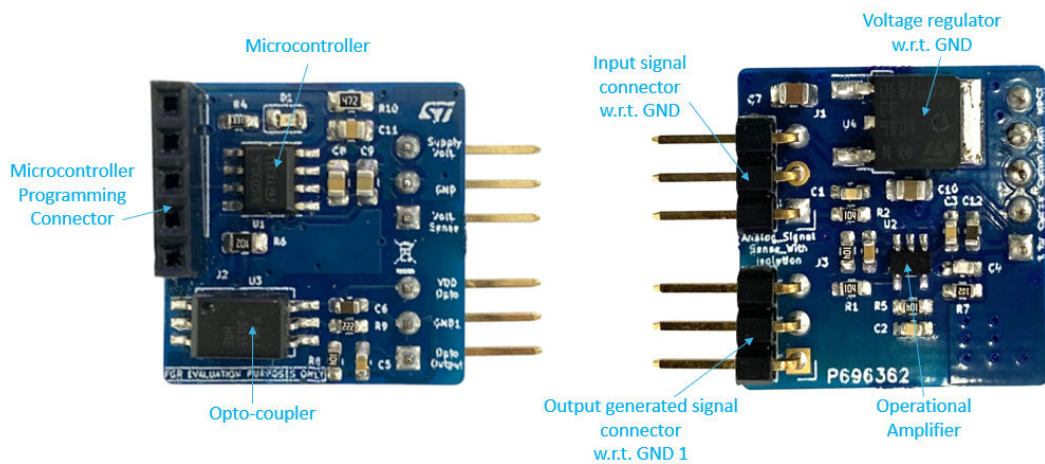
The analog signal, which is to be measured, is fed at non-inverting input of the operational amplifier, that not only provides high impedance input, but is also used for gain, if required. The signal is then sampled at the analog to digital converter (ADC) peripheral of the microcontroller. The operational amplifier and microcontroller are referred to the same ground (GND) as that of measured analog signal, as shown in Figure 3.

Depending on the ADC value, the microcontroller generates pulse width modulation (PWM), which is an input to the optocoupler. The optocoupler provides the isolation required, and the PWM generated with respect to another ground (GND 1) is passed through the RC filter. The output measurement after the RC filter w.r.t. GND 1 matches fairly accurately with the input analog signal measured w.r.t. GND.

The board pictures have been highlighted in Figure 1 and Figure 2, while the details of firmware and testing results are highlighted in subsequent sections.

1.1 Key components

Figure 4. Key components used on the daughter board



2 Electrical specifications

Table 1. Electrical specifications of the daughter board

Parameters	Range
Input voltage supply - primary	5 ~ 24 V
Analog sense signal voltage range	0 ~ 3.3 V DC
Opto-coupler input voltage – secondary	3.3 V DC
Output signal accuracy	> 98%

The operational amplifier is configured for unity gain buffer by default, as per the Schematic diagrams. The gain of the operational amplifier can be adjusted using R1 and R5 resistances.

The value of resistance R3 must be the same as that of resistance R5.

The gain of the differential operational amplifier can be calculated with the below equation.

$$Gain = \frac{R5}{R1} \cdot (V_{non-inverting} - V_{inverting})$$

$$Gain = \frac{R5}{R1} \cdot (V_{sense} - 0)$$

$$Gain = \frac{R5}{R1} \cdot (V_{sense})$$

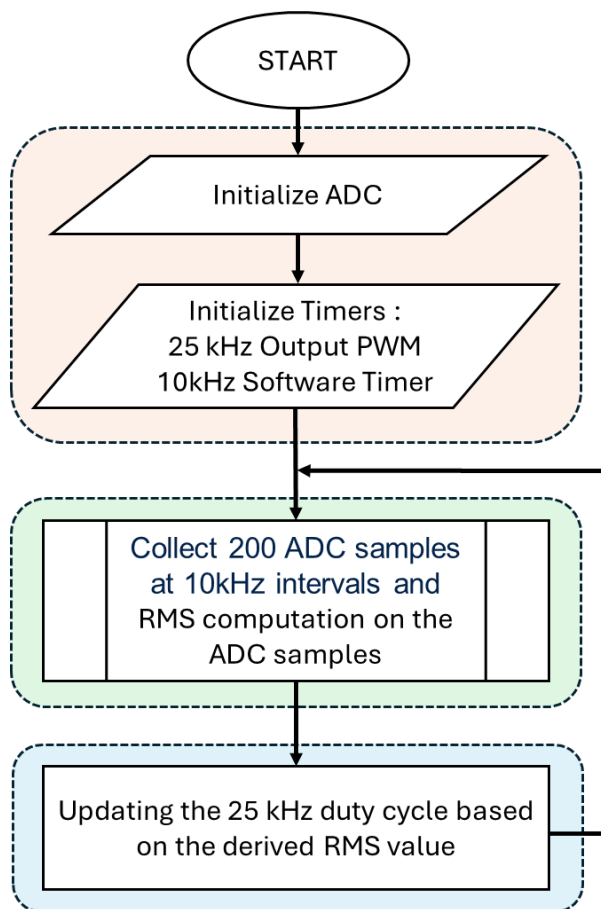
3 Firmware

The STM32G030 microcontroller has been configured to sample ADC signal at 10 kHz frequency. It computes 200 samples and it calculates the root mean square (RMS) value. The microcontroller also generates a 25 kHz PWM signal. The duty cycle of the PWM is governed by the calculated RMS value of the sensed signal. The firmware flowchart is highlighted in [Figure 5](#).

The STM32G030 microcontroller is equipped with 12-bit ADC peripheral. The output PWM duty cycle is calculated with the following expression:

$$\text{Duty cycle of 25 kHz} = \frac{\text{Calculated RMS value} \cdot \text{TIMER}(25\text{kHz})_{\text{ARR}}}{2^{12}} = \frac{\text{RMSvalue} \cdot \text{TIMER}(25\text{kHz})_{\text{ARR}}}{4096}$$

Figure 5. Firmware flowchart



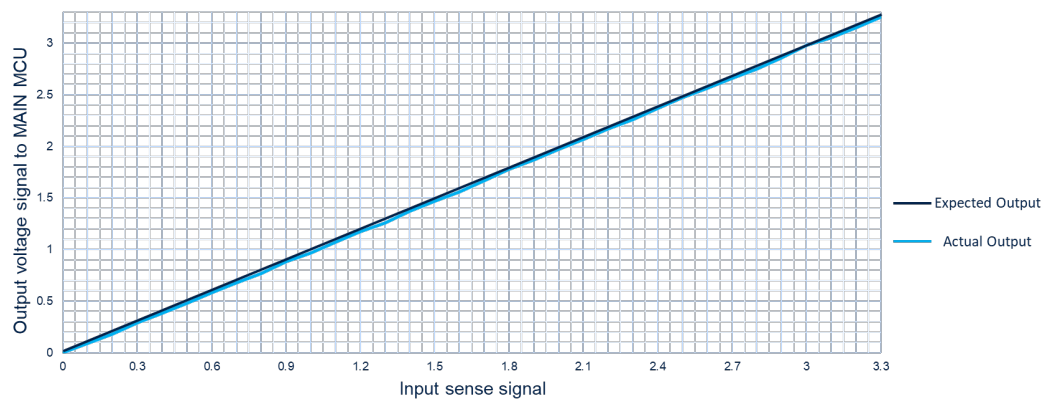
4 Test results and waveforms

4.1 Test results

A graph between input sense signal and output voltage signal has been highlighted in Figure 6. It can be observed that the daughter board output signal is roughly the same as that of input sense signal, with an accuracy above 98%.

Figure 6. Input sense signal vs output signal from microcontroller

Input sense signal vs Output voltage generated signal to MAIN MCU



4.2 Waveforms

Below are the waveforms, highlighting the change in the output signal based on different input sense signals. In order to optimize the speed, number of samples, sampling frequency, and output signal, PWM frequency can be altered in the firmware.

Figure 7. Input sense signal (yellow) vs output signal generated (blue) - Transition from 0 to 1 V



Figure 8. Input sense signal (yellow) vs output signal generated (blue) - Transition from 0 to 2 V



Figure 9. Input sense signal (yellow) vs output signal generated (blue) - Transition from 0 to 3.3 V



5 Use cases

Before the signal is sensed by the microcontroller, the analog signal is fed to the operational amplifier. The default resistors (R1, R3, and R5) values have been selected to have gain equal to 1.

5.1 Voltage signal sense

Example: 2 V analog signal sense.

The non-inverting input of operational amplifier sees the voltage level of 2 V. As this signal has decent amplitude, the default unity gain configuration of the operational amplifier can be used.

The microcontroller takes 200 samples at a 10 kHz interval and perform RMS computation. Based on the RMS computation result, the 25 kHz PWM duty cycle is calculated as highlighted in [Section 3](#). For 2 V signal, the duty cycle is approximately 60.6%. This PWM passes through the RC (R9, C5) filter, providing stable reading at the output.

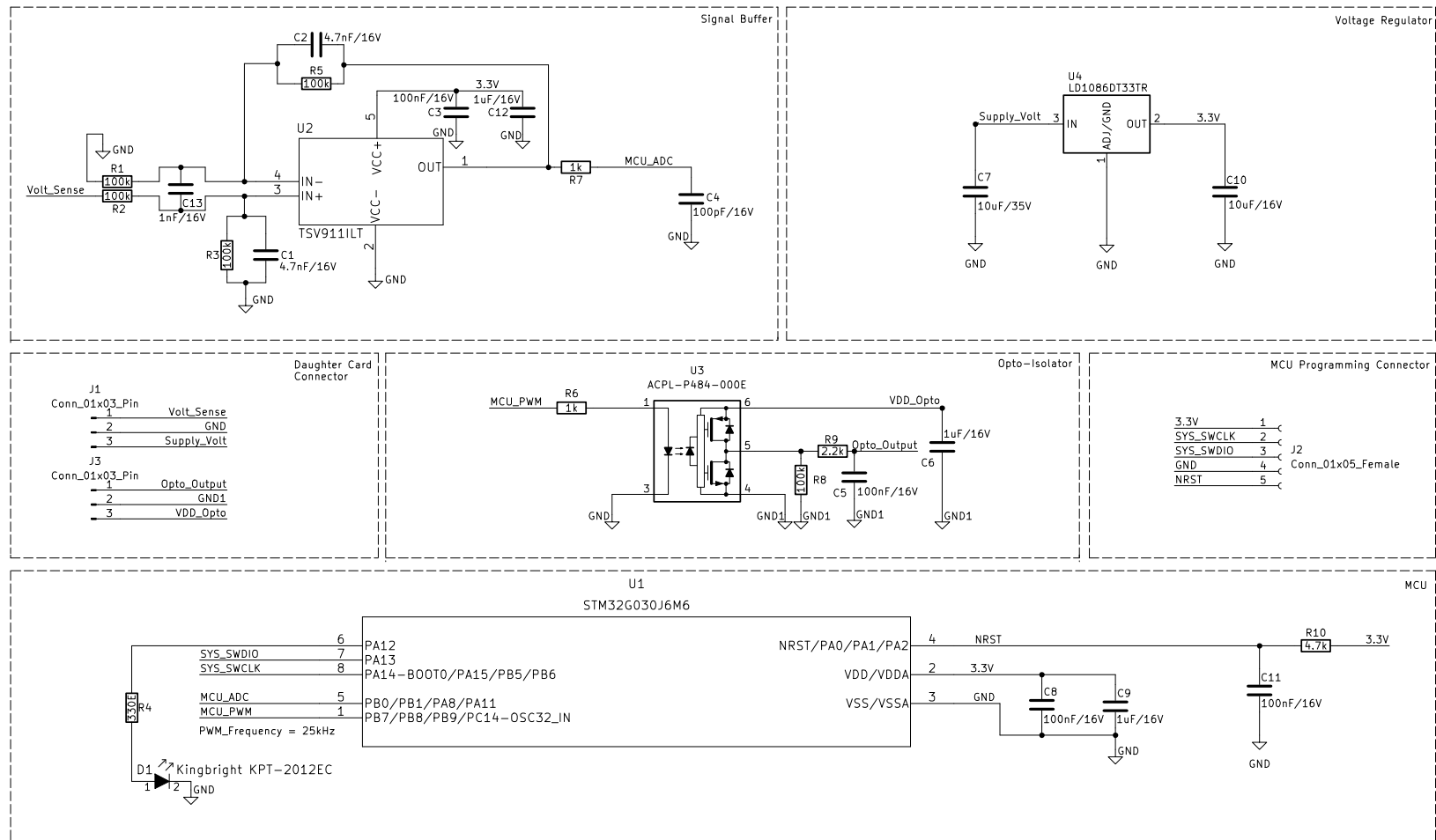
5.2 Current signal sense

Example: 10 A through 5 M Ω shunt resistor.

The voltage across the shunt and the non-inverting input of operational amplifier see the voltage level of 50 mV ($10\text{A} \times 5\text{M}\Omega$), which has quite a low amplitude. Using resistors (R1, R3, and R5), the gain of the operational amplifier can be increased to have a signal, which can be measured at the desired voltage level.

In this case, the gain 20 has been selected, so R3 and R5 need to be changed to 2 M Ω , while R1 should be 100 k. By applying these changes, the 50 mV (original analog signal) gives the input of microcontroller ADC peripheral of 1 V. The microcontroller takes 200 samples at a 10kHz interval and perform RMS computation. Based on the RMS computation result, the 25 kHz PWM duty cycle is calculated as highlighted in [Section 3](#). For 1 V signal, the duty cycle is approximately 30.3%. This PWM passes through the RC (R9, C5) filter, giving stable reading at the output.

Figure 10. Daughter board circuit schematic



7 PCB layout

Figure 11. Board layout - top

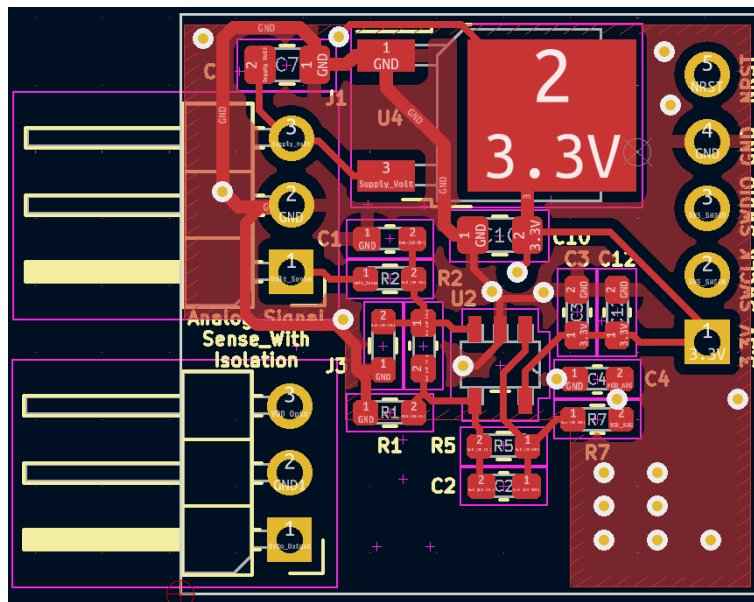
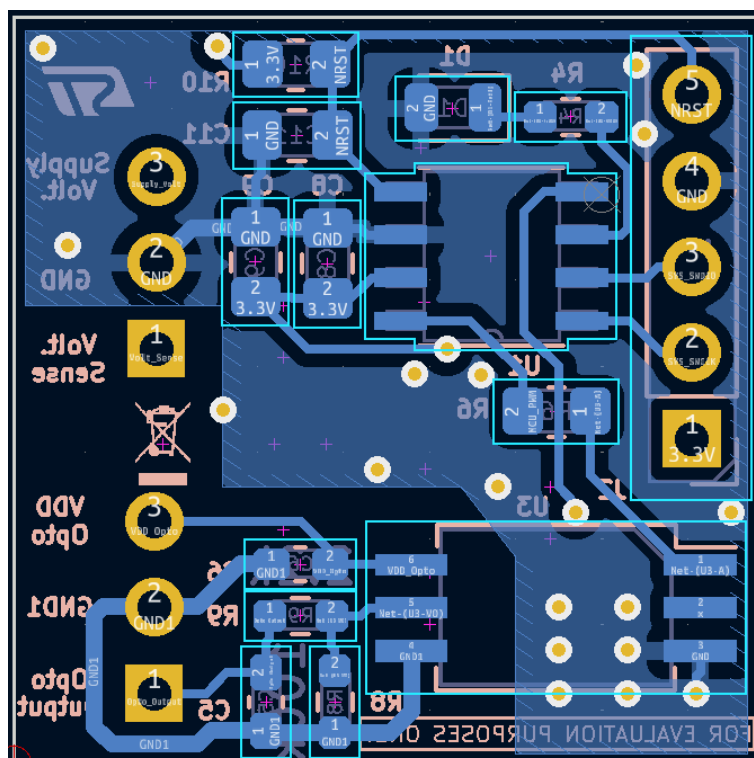


Figure 12. Board layout - bottom



8 Bill of materials

Table 2. Daughter board bill of materials

Item	Q.ty	Ref.	Part/value	Description	Manufacturer	Order code
1	2	C1,C2	4.7nF	Ceramic Capacitor X7R	Wurth Elektronik	885012206038
2	1	C4	100pF	Ceramic Capacitor X7R	Wurth Elektronik	885012206028
3	2	C8,C11	100nF	Ceramic Capacitor X7R	Wurth Elektronik	885012207045
4	2	C3,C5	100nF	Ceramic Capacitor X7R	Wurth Elektronik	885012206046
5	1	C9	1uF	Ceramic Capacitor X7R	Wurth Elektronik	885012207051
6	2	C6,C12	1uF	Ceramic Capacitor X7R	Wurth Elektronik	885012206052
7	1	C7	10uF	Ceramic Capacitor X7R	TAIYO YUDEN	EMK212BB7106KG-T
8	1	C10	10uF	Ceramic Capacitor	TAIYO YUDEN	MSASG21GBB5106KTNA01
9	1	C13	1nF	Ceramic Capacitor X7R	Wurth Elektronik	885012206034
10	1	D1	Red Led	Red Color LED	Kingbright	APT2012EC
11	1	J1	Connector 01x06_Male_Right_Angle	Connector 2.54mm Pitch	Wurth Elektronik	61300611021
12	1	J2	Connector_01x05_Female	Connector 2.54mm Pitch	Samtec	CES-105-02-G-S
13	5	R1,R2,R3,R5,R8	100k	Thick Film Resistor	Vishay	CRCW0603100KFHEAP
14	1	R6	1k	Thick Film Resistor	Vishay	RCA08051K00FKEAHP
15	1	R7	1k	Thick Film Resistor	Vishay	CRCW06031K00FKEA
16	1	R4	330E	Thick Film Resistor	Vishay	CRCW0603330RFKEC
17	1	R9	2.2k	Thick Film Resistor	Vishay	CHP0603K2201FBT
18	1	R10	4.7k	Thick Film Resistor	Vishay	CRCW08054K70FKEC
19	1	U1	STM32G030J6M6, SO-8	Arm® Cortex®-M0+ 32-bit MCU	ST	STM32G030J6M6
20	1	U2	TSV9111LT, SOT23-5L	8 MHz operational amplifiers	ST	TSV9111LT
21	1	U3	ACPL-P484-000E	High-speed optocoupler	Broadcom	ACPL-P484-000E
22	1	U4	LD1086DT33TR, DPAK	Low drop voltage regulator	ST	LD1086DT33TR

9 Conclusion

The goal of this technical note is to highlight a method to sense analog signal at the ADC peripheral of the MCU with isolation, as in the case of [STDES-2KW5CH48V](#), where primary DC BUS voltage needs to be sensed at the microcontroller referenced at secondary ground.

The components used in the Schematic diagrams can be altered as per user specific needs. For example, a voltage regulator of less quiescent current or smaller package can be used to effectively reduce PCB size.

Appendix A Reference design warnings, restrictions and disclaimer

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Revision history

Table 3. Document revision history

Date	Revision	Changes
07-Jul-2025	1	Initial release.

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